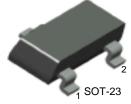


# KST05/06

### **Driver Transistor**

- Collector-Emitter Voltage: V<sub>CEO</sub> = KST05: 60V
- KST06: 80V
- Collector Dissipation:  $P_C$  (max) = 350mW
- Complement to KST55/56



1. Base 2. Emitter 3. Collector

## **NPN Epitaxial Silicon Transistor**

## Absolute Maximum Ratings Ta=25°C unless otherwise noted

Symbol	Parameter	Value	Units
V <sub>CBO</sub>	Collecto-Base Voltage		
	: KST05	60	V
	: KST06	80	V
V <sub>CEO</sub>	Collector-Emitter Voltage		
	: KST05	60	V
	: KST06	80	V
V <sub>EBO</sub>	Emitter-Base Voltage	4	V
I <sub>C</sub>	Collector Current	500	mA
P <sub>C</sub>	Collector Dissipation	350	mW
T <sub>STG</sub>	Storage Temperature	150	°C
R <sub>TH</sub> (j-a)	Thermal Resistance junction to Ambient	357	°C/W

## Electrical Characteristics Ta=25°C unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Max.	Units
BV <sub>CEO</sub>	* Collector-Emitter Breakdown Voltage : KST05	I <sub>C</sub> =1mA, I <sub>B</sub> =0	60		V
	: KST06	IC-1111, B-0	80		v
BV <sub>EBO</sub>	Emitter-Base Breakdown Voltage	I <sub>E</sub> =100μA, I <sub>C</sub> =0	4		V
I <sub>CBO</sub>	Collector Cut-off Current : KST05 : KST06	V <sub>CB</sub> =60V, I <sub>E</sub> =0 V <sub>CB</sub> =80V, I <sub>E</sub> =0		0.1 0.1	μΑ μΑ
I <sub>CEO</sub>	Collector Cut-off Current	V <sub>CE</sub> =60V, I <sub>B</sub> =0		0.1	μA
h <sub>FE</sub>	DC Current Gain	V <sub>CE</sub> =1V, I <sub>C</sub> =10mA V <sub>CE</sub> =1V, I <sub>C</sub> =100mA	50 50		
V <sub>CE</sub> (sat)	Collector-Emitter Saturation Voltage	I <sub>C</sub> =100mA, I <sub>B</sub> =10mA		0.25	V
V <sub>BE</sub> (on)	Base-Emitter On Voltage	V <sub>CE</sub> =1V, I <sub>C</sub> =100mA		1.2	V
f <sub>T</sub>	Current Gain Bandwidth Product	V <sub>CE</sub> =2V, I <sub>C</sub> =100mA, f=100MHz	100		MHz

\* Pulse Test: PW≤300µs, Duty Cycle≤2%

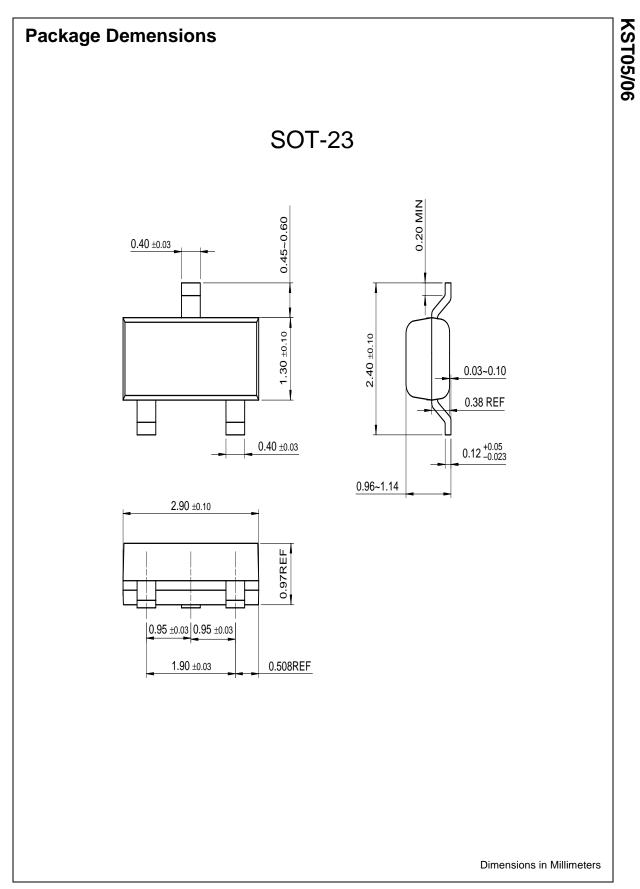
## **Marking Code**

Туре	KST05	KST06
Mark	1H	1G



Marking

日 1H



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